



SINGLE P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	40mΩ @ V _{GS} = -4.5V	-6.5A
-30V	70mΩ @ V _{GS} = -2.5V	-5.0A

Description

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

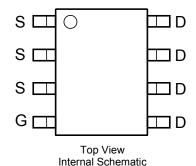
Features and Benefits

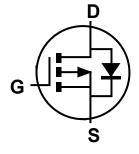
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Weight: 0.074g (approximate)







Equivalent circuit

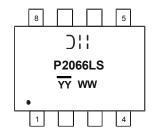
Ordering Information (Note 4)

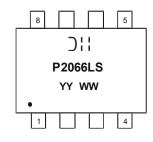
Part Number	Case	Packaging
DMP2066LSS-13	SO-8	2500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





)|| = Manufacturer's Marking P2066LS = Product Type Marking Code YYWW = Date Code Marking YY or YY = Year (ex: 13 = 2013) WW = Week (01 - 53)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)

Shanghai A/T Site



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage		V _{DSS}	-20	V	
Gate-Source Voltage		V _{GSS}	±12	V	
Drain Current (Note 5)	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-6.5 -5.2	Α
Pulsed Drain Current (10µs pulse, duty cycle = 1%)		I _{DM}	-26	Α	

Thermal Characteristics

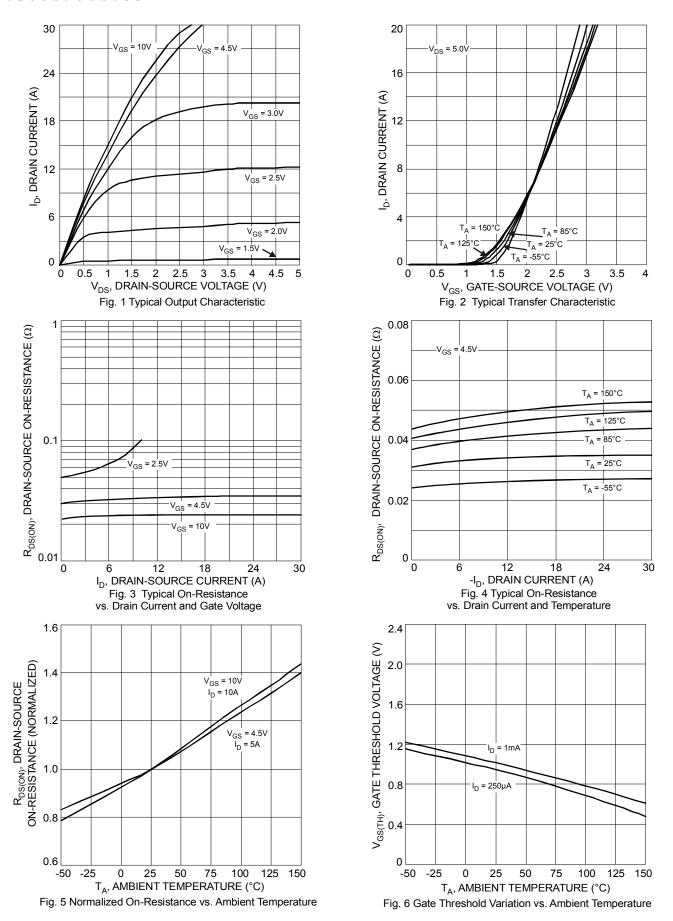
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	2.5	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ hetaJA}$	50	°C/W
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

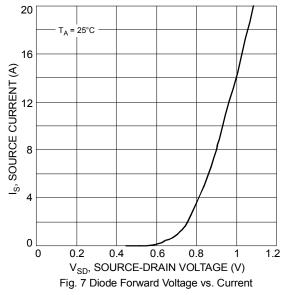
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)					•	·
Gate Threshold Voltage	V _{GS(th)}	-0.6	_	-1.2	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	Б	_	_	40	mΩ	$V_{GS} = -4.5V$, $I_D = -5.8A$
Static Dialii-Source Off-Resistance	R _{DS (ON)}	_	_	70	111122	$V_{GS} = -2.5V$, $I_D = -3.8A$
Forward Transconductance	g _{fs}	_	9	_	S	$V_{DS} = -10V, I_D = -4.6A$
Diode Forward Voltage	V_{SD}	-0.5	-0.72	-1.4	V	$V_{GS} = 0V, I_{S} = -2.1A$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C _{iss}	_	820	_	pF	45)/)/ 0)/
Output Capacitance	Coss	_	200	_	pF	V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	160	_	pF	
Gate Resistance	Rg	_	10.4	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, f = 1.0MHz
Total Gate Charge	Qg	_	14.4	_		10)/)/ 45)/
Gate-Source Charge	Qgs	_	2.6	_	nC	$V_{DS} = -10V, V_{GS} = -4.5V$ $I_{D} = -4.5A$
Gate-Drain Charge	Q _{gd}	_	2.7	_		
Turn-On Delay Time	t _{D(on)}	_	13.7	_		V_{DD} = -10V, V_{GS} = -4.5V, R_{G} = 6 Ω , R_{L} = 10 Ω , I_{D} = -1A
Turn-On Rise Time	t _r	_	14.0	_	no	
Turn-Off Delay Time	t _{D(off)}	_	79.1	_	ns	
Turn-Off Fall Time	t _f	_	35.5	_		

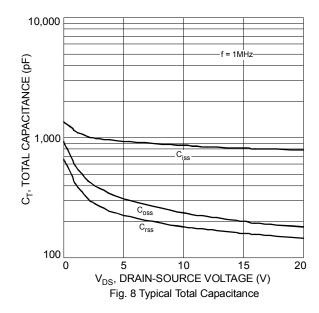
- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.6. Short duration pulse test used to minimize self-heating effect.7. Guaranteed by design. Not subject to product testing.

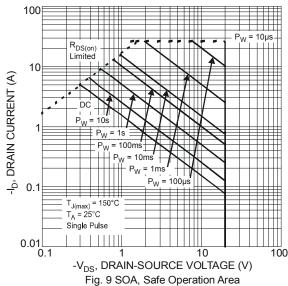






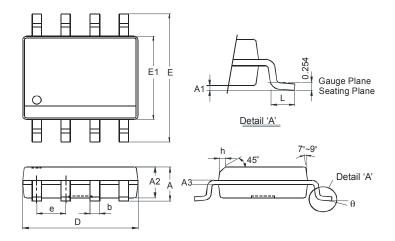






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

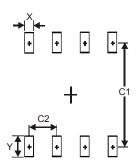


SO-8				
Dim	Min	Max		
Α	-	1.75		
A1	0.10	0.20		
A2	1.30	1.50		
A3	0.15	0.25		
b	0.3	0.5		
D	4.85	4.95		
Е	5.90	6.10		
E1	3.85	3.95		
е	1.27 Typ			
h	-	0.35		
٦	0.62	0.82		
θ	0°	8°		
All Dimensions in mm				



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

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